# N-Channel 60-V (D-S) MOSFET

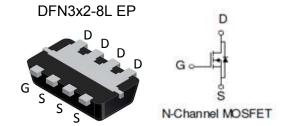
### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- Low thermal impedance
- · Fast switching speed
- Small Footprint DFN3x2-8L package

### **Typical Applications:**

- Telecom DC/DC converters
- · White LED boost converters
- Industrial DC/DC conversion
- Automotive Entertainment and GPS DC/DC conversion

PRODUCT SUMMARY				
V <sub>DS</sub> (V)				
60	82 @ V <sub>GS</sub> = 10V	5		
00	115 @ V <sub>GS</sub> = 4.5V	4.1		



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Limit	Units				
Drain-Source Voltage			60	V			
Gate-Source Voltage	$V_{GS}$	±20	V				
Continuous Drain Current a	T <sub>A</sub> =25°C	I_	5				
Continuous Drain Current	T <sub>A</sub> =70°C	I <sub>D</sub>	3.7	Α			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	30				
Continuous Source Current (Diode Conduction) a		I <sub>S</sub>	4.3	Α			
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	3.5	W			
Power dissipation	T <sub>A</sub> =70°C	' D	2	V V			
Operating Junction and Storage Temperature Range		$T_J,T_stg$	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	35	°C/W			
IMAXIIIIUIII SUIICIIOII-IO-AIIIDIEIII	Steady State	IN <sub>θ</sub> JA	81				

### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

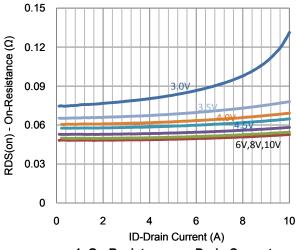
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	Source Threshold Voltage $V_{GS(th)}$ $V_{DS} = V_{GS}$ , ID = 250 uA				3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
Drain Source On Begintance	r	$V_{GS} = 10 \text{ V}, I_{D} = 4 \text{ A}$			82	mO.	
Drain-Source On-Resistance	Γ <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 3.3 \text{ A}$			115	mΩ	
Forward Transconductance	$g_{fs}$	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 4 A		10		S	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 2.1 A, V <sub>GS</sub> = 0 V		0.77		V	
Dynamic							
Total Gate Charge	$Q_g$			4.1			
Gate-Source Charge	$Q_gs$	$V_{DS} = 30 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 4 \text{ A}$		1.2		nC	
Gate-Drain Charge	$Q_{gd}$			1.4		1	
Turn-On Delay Time	$t_{d(on)}$			2.5			
Rise Time	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 7.5 $\Omega$ , $I_D$ = 4 A,		4.1		20	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		12.1		nS	
Fall-Time	t <sub>f</sub>			4.5			

#### **Notes**

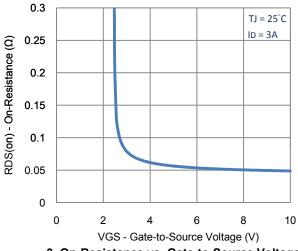
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

Analog Power (APL) reserves the right to make changes without further notice to any products herein. APL makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does APL assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in APL data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. APL does not convey any license under its patent rights nor the rights of others. APL products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the APL product could create a situation where personal injury or death may occur. Should Buyer purchase or use APL products for any such unintended or unauthorized application, Buyer shall indemnify and hold APL and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that APL was negligent regarding the design or manufacture of the part. APL is an Equal Opportunity/Affirmative Action Employer.

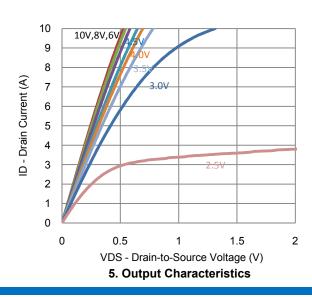
# **Typical Electrical Characteristics**

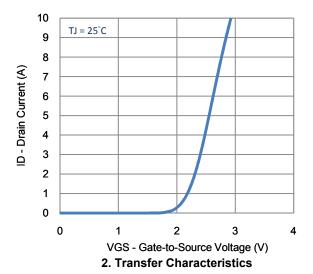


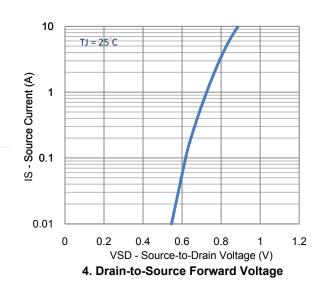
#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage

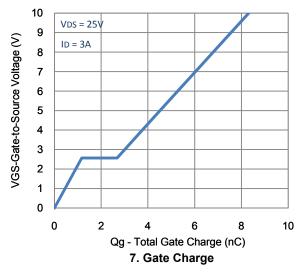


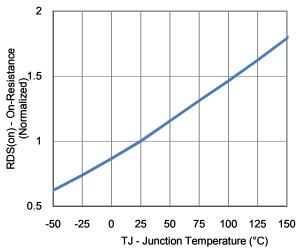


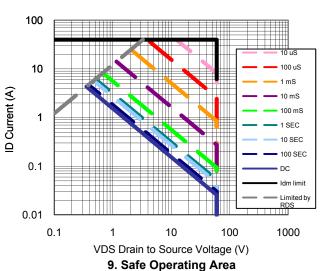


600 F = 1MHz 500 Ciss Capacitance (pf) 400 300 200 Coss 100 Crss 0 0 10 20 VDS-Drain-to-Source Voltage (V) 6. Capacitance

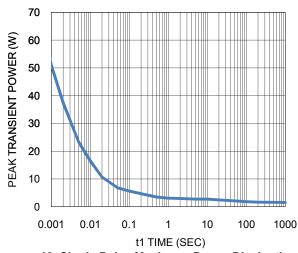
### **Typical Electrical Characteristics**



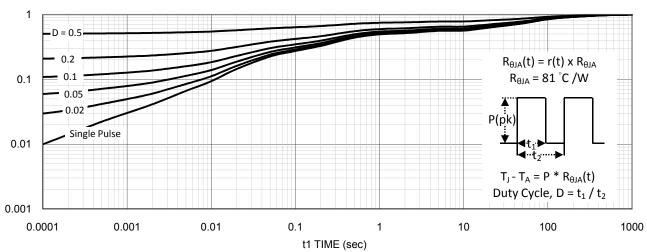






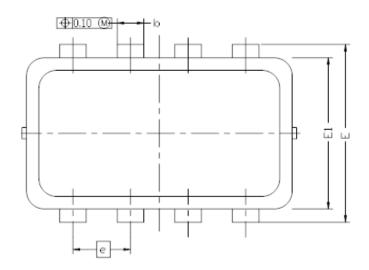


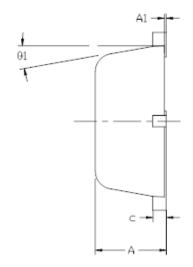
10. Single Pulse Maximum Power Dissipation

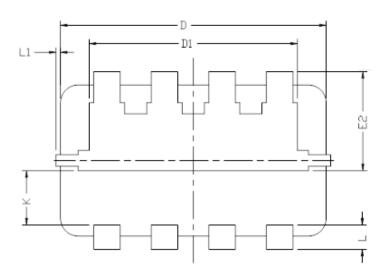


11. Normalized Thermal Transient Junction to Ambient

# **Package Information**







DIM.	MILLIMETERS			INCHES			
DII'I.	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0.700	0.80	0.900	0.0276	0.0315	0.0354	
A1	0.00		0.05	0.000		0.002	
b	0.24	0.30	0.35	0.009	0.012	0.014	
С	0.08	0.152	0.25	0.003	0.006	0.010	
D	3.00 BSC			0.118 BSC			
D1	2.30	2.35	2.40	0.091	0.093	0.095	
E	2.00 BSC			0.079 BSC			
E1	1.70 BSC			0.067 BSC			
E5	1.065	1.115	1.165	0.042	0.044	0.046	
6	0	0.65 BSC			0.026 BSC		
L	0.20	0.275	0.400	0.008	0.011	0.0157	
K	0.56	0.61	0.66	0.022	0.024	0.026	
L1	0		0.100	0		0.004	
91	0?	10?	12?	0?	10?	12?	

#### Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.